	ESC		DOCUMENT	CHANGE REQUEST
DCR number	1077	Changes required for:	General	Originator: Geraldine Chaumont
Date: 2017/05/24 Date sent: 2017/03/29				Organisation: STMicroelectronics
Status: IMPLE	MENTED			
Title:	Transistors Matched Dual PNP, based on types 2N3810 and 2N3811			
Number:	5207/005	Issue:	4	
Other documents affected:				
Page:				
5 and 16				
Paragraph:				
1.4.1 and 1.4.2 + 2.10 to add				
Original wording:				
No irradiation data included in the detail specifications.				
Proposed wording:				
Insertion of a radiation level + total dose radiation chapter, as done in DCR707 and 757 for other detail specifications.				
Justification:				
The customers are asking for radiation level on bipolar transistors.				
Attachments:				
dcrxxx_attachment_rev0(2).docx				
Modifications:				
N/A				
Approval signature:				
R. C. Hari-1				
Date signed:				
2017-05-24				